

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value_Q1	Value_Q2	Unit
Drain-Source Voltage			V _{DSS}	30	-30	V
Gate-Source Voltage			V _{GSS}	±20	±20	V
Continuous Drain Current (Note 6) Q1: $V_{GS} = 10V$ Q2: $V_{GS} = -10V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		0.8 0.6	-0.55 -0.44	A
Maximum Continuous Body Diode Forward Current (Note 6)			ls	0.4	-0.38	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	4	-2.4	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.29	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	433	°C/W
Total Power Dissipation (Note 6)		PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	301	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics – N Channel – Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						-	
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1.0	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.8	1.2	1.6	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	- 0.2 0.4	Ω	$V_{GS} = 10V, I_D = 0.59A$				
	R _{DS(ON)}	-	0.3	0.7	12	$V_{GS} = 4.5V, I_D = 0.2A$	
Diode Forward Voltage	V _{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 0.1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	-	50	-	pF		
Output Capacitance	Coss	-	12	-	pF	$V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	-	10	-	pF	1 = 1.00012	
Gate Resistance	R _g	-	58	-	Ω	$V_{DS} = V_{GS} = 0V$, f = 1.0MHz	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	0.5	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	-	1.2	-	nC	$V_{DS} = 10V, I_D = 250mA$	
Gate-Source Charge	Q _{gs}	-	0.2	-	nC	$v_{DS} = 10v, i_D = 250 \text{mA}$	
Gate-Drain Charge	Q _{gd}	-	0.1	-	nC		
Turn-On Delay Time	t _{D(ON)}	-	3.5	-	ns		
Turn-On Rise Time	t _R	-	3.3	-	ns	$V_{GS} = 10V, V_{DS} = 30V,$	
Turn-Off Delay Time	t _{D(OFF)}	-	16.8	-	ns	$I_D = 100 \text{mA}, R_G = 25 \Omega$	
Turn-Off Fall Time	tF	-	13.8	-	ns		

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



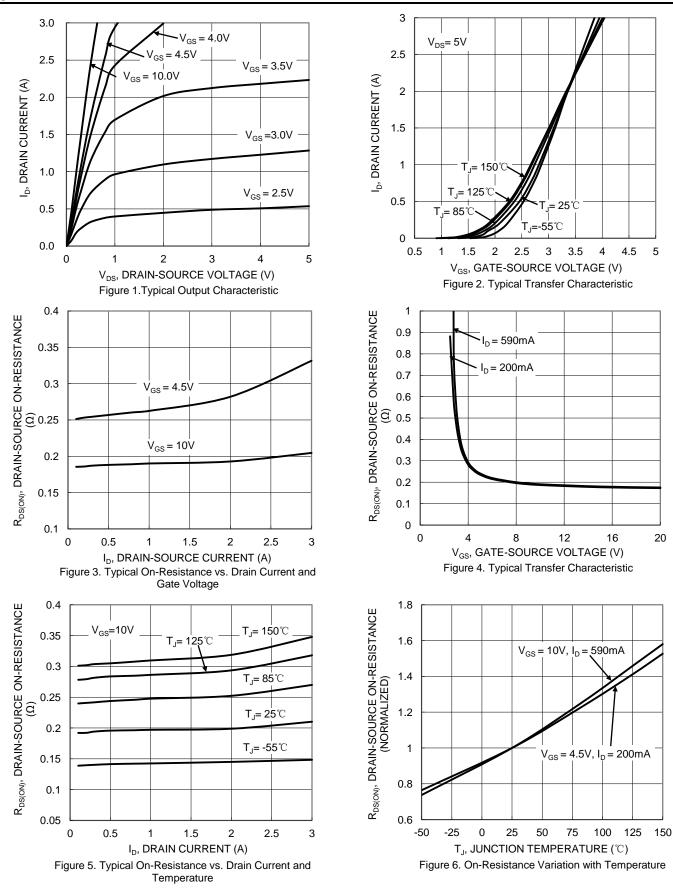
Electrical Characteristics – P Channel – Q2 (@T_A = +25°C, unless otherwise specified.)

			-				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	-	-	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	-1	μA	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	-	-	±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-1	-2.2	-2.6	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		-	0.5	0.9	Ω	$V_{GS} = -10V, I_D = -0.42A$	
	R _{DS(ON)}	-	0.78	1.7		$V_{GS} = -4.5V, I_D = -0.2A$	
Diode Forward Voltage	V _{SD}	-	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -0.23A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	-	19	-	pF		
Output Capacitance	Coss	-	16	-	pF	[−] V _{DS} = -15V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance	Crss	-	3	-	pF		
Gate Resistance	Rg	-	4.4	-	kΩ	$V_{DS} = V_{GS} = 0V$, f = 1.0MHz	
Total Gate Charge (V _{GS} = -4.5V)	Qg	-	0.36	-	nC	V _{DS} = -10V, I _D = -0.24A	
Total Gate Charge (V _{GS} = -10V)	Qg	-	0.8	-	nC		
Gate-Source Charge	Q _{gs}	-	0.1	-	nC		
Gate-Drain Charge	Q _{gd}	-	0.1	-	nC		
Turn-On Delay Time	t _{D(ON)}	-	3.3	-	ns		
Turn-On Rise Time	t _R	-	2.3	-	ns	V _{GS} = -10V, V _{DD} = -15V,	
Turn-Off Delay Time	t _{D(OFF)}	-	406	-	ns	$I_{D} = -0.5A, R_{G} = 1\Omega$	
Turn-Off Fall Time	t _F	-	237	-	ns]	

Notes:7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.

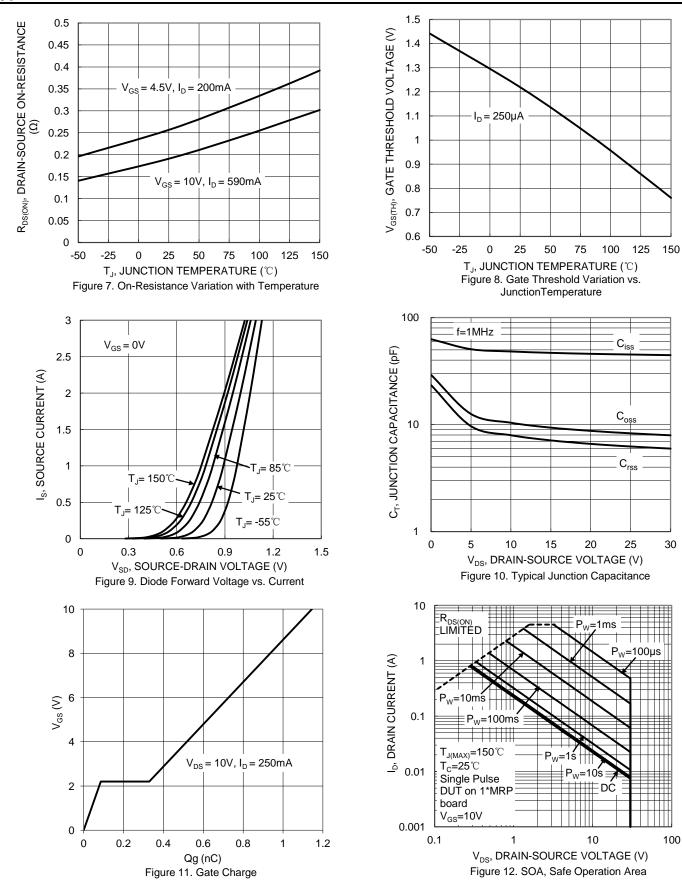


Typical Characteristics - N-CHANNEL



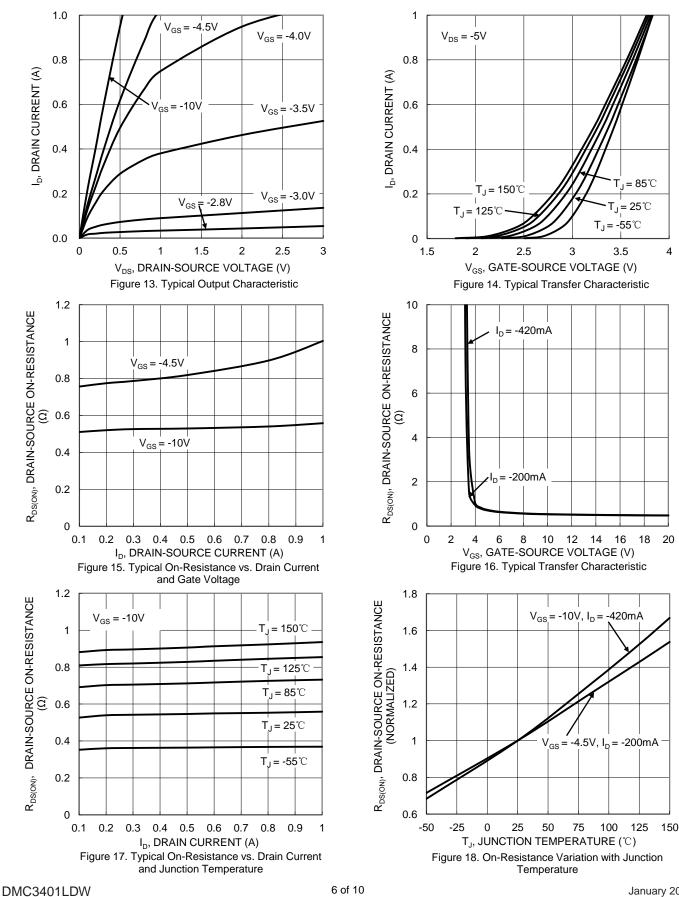


Typical Characteristics - N-CHANNEL (Cont.)





Typical Characteristics - P-CHANNEL

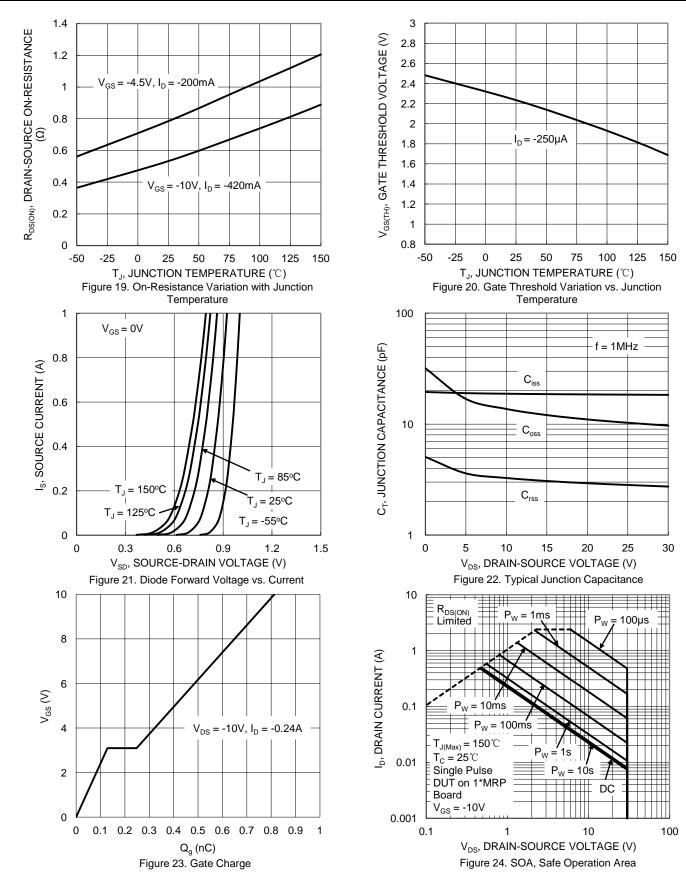


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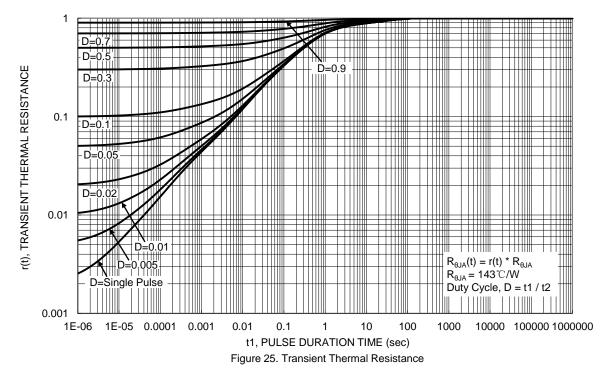
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Typical Characteristics - P-CHANNEL (Cont.)



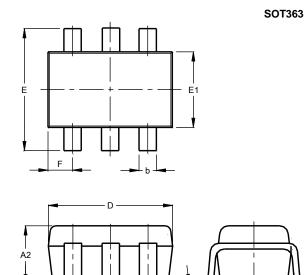






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

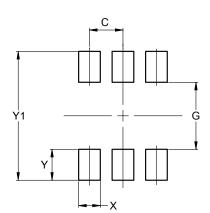


SOT363						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.10	0.30	0.25			
C	0.10	0.22	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	0.650 BSC					
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

A1

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	1.300			
X	0.420			
Y	0.600			
Y1	2.500			

SOT363



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